

ioDrive Octal Capacity	5.12TB		
NAND Type	MLC (Multi Level Cell)		
Read IOPS (512 B)	1,190,000		
Write IOPS (512 B)	1,180,000		
75/25 Mix IOPS (512 B)	729,000		
Read Bandwidth (64 kB)	6.0 GB/s		
Write Bandwidth (64 kB)	4.4 GB/s		
Access Latency (512 Byte)	30 μs		
Bus Interface	PCI-Express x16 Gen2.0		
Operating Systems	64-Bit Microsoft Server 2003/2008, 64-Bit Microsoft Windows XP/Vista/Win7, RHEL 4/5/6, SLES 10/11, OEL v4/v5, VMware ESX 4.0/4.1		

AGENCY

US / Canada	ANSI C63.4/EN 55022/ CNS 13438, Radiated and Conducted Emissions Class A EN 55024 Immunity EN 55022 Class A		
Europe	2004/108/EC EMC Directive CE IEC 61000 Class A Mark		
Japan	VCCI - V-2/2009.04		
Taiwan	BSMI - CNS 13438 / EN 55022 class A		
New Zealand/Australia	AS/NZS CISPR22:2006 / 47CFR Part 15, Radiated and Conducted Emissions Class A		
Korea	KCC – FIO-IODRIVE (Class A)		
RoHS	RoHS – EU Directive 2002/95/EC		

STANDARDS Form Foster

Form Factor	PCI Express x16 Gen 2.0 Double Wide		
Connectivity	PCI Express electromechanical spec 2.0		
Power	PCI Express power spec 2.0		
Max Power Consumption	150w		
Required Power Connections	(1) 8-Pin PCle 150w connector or		
Required Fower Connections	(2) 6-Pin PCIe 75w connectors		

ENVIRONMENTAL SPECIFICATIONS

		Min	Max
Tananaratura / C*	Operational	0	55
Temperature (C)*	Non-operational	-40	70
Air Flow (LFM)		300	
Humidity (%)	Non-condensing	5	95
Altitude	Operational		10,000
Attitude	Non-operational		30,000

^{*} Temperate derated 1 C per 1000 ft elevation above sea level 100% Designed and Assembled in the U.S.A.



